

LOW-SATURATION VOLTAGE TR SERIES(Small-Signal Transistors.N.O.1)

The low-saturation voltage TR series, being excellent in VCE(sat) and switching characteristic at high current, are suited for use in inverters, converters, power amplifiers, electrical equipment. We have a full lineup of new products fabricated using Sanyo's original MBIT process technology. They can be applied to various uses because of high quality and small-sized package.

Features

- ◆ Large current capacity.
- ◆ Low saturation voltage.
- ◆ Short switching time.
- ◆ Highly resistant to breakdown.
- ◆ Low noise design.
- ◆ Possible to make sets smaller.

Application areas

- * Radio cassette recorders, electronic governors, strobes, cameras, relay drivers, lamp drivers, audio circuits, hammer drivers, voltage regulators, fluorescent lamps, motor drivers, video equipment, microcomputers peripheral.

In addition to the above, the low-saturation voltage TR, Large signal TR series and PCP/5,NMP : package series are available.

(*)MBIT process technology "New manufacturing method, Multi Base Island Transistors"

*:Tc=25°C. ☆:Mounted on PCB (250mm²×0.8mm).

●:Contains base to emitter resistance(RBE).

For PNP, (-) sign is omitted.

Type No.	Pack- age	Absolute Maximum Ratings/Ta=25°C				Electrical Characteristics/Ta=25°C					
		V _{CBO} (V)	V _{CEO} (V)	I _C (A)	P _C (W)	V _{CE} (V)	I _C (A)	h _{FE}	I _C (A)	I _B (A)	V _{CE(sat)} typ (V)
2SA1745/2SC4555	CP	20	15	0.5	0.15	2	10mA	135~600	5mA	0.5mA	15mA
2SA1753/2SC4577		20	15	0.5	0.2	2	10mA	135~600	5mA	0.5mA	15mA
2SA1881/2SC4983		15	15	1	0.25	2	50mA	135~600	5mA	0.5mA	10mA
2SB815/2SD1048		20	15	0.7	0.2	2	50mA	200~600/200~900	5mA	0.5mA	15mA/10mA
2SB1295/2SD1935		15	15	0.8	0.2	2	50mA	135~600/135~900	5mA	0.5mA	10mA
/2SD2028		11±3	0.7	0.2		2	50mA	200~900	0.1	10mA	50mA
2SB1527/2SD2324		20	15	0.8	0.2	2	0.5	min70 RBE=typ1kΩ	0.5	10mA	0.2/0.16
2SA1882/2SC4984	PCP	15	15	1.5	☆1.3	2	50mA	140~560	5mA	0.5mA	10mA
2SA1896		25	20	2.5	☆1.3	2	0.5	140~400	1.5	30mA	0.22
2SB1118/2SD1618		20	15	0.7	☆1.3	2	50mA	140~560	5mA	0.5mA	15mA/10mA
2SB1119/2SD1619		25	25	1	☆1.3	2	50mA	100~560	0.5	50mA	0.15/0.1
2SB1120		20	10	2.5	☆1.3	2	0.5	100~560	1.5	0.15	0.25
2SB1121/2SD1621*		30	25	2	☆1.3	2	0.1	100~560	1.5	75mA	0.35/0.18
2SB1122/2SD1622*		60	50	1	☆1.3	2	0.1	100~560	0.5	50mA	0.18/0.12
2SB1123/2SD1623*		60	50	2	☆1.3	2	0.1	100~560	1	50mA	0.3/0.15
2SB1124/2SD1624*		60	50	3	☆1.5	2	0.1	100~560	2	0.1	0.35/0.19
2SB1323/2SD1997		40	30	3	☆1.5	2	0.5	min70 RBE=typ0.8kΩ	1	50mA	0.18/0.12
2SB1324/2SD1998		40	30	3	☆1.5	2	0.5	min70 RBE=typ0.8kΩ	2	0.1	0.25/0.2
2SB1325/2SD1999		25	20	4	☆1.5	2	0.5	min70 RBE=typ1.5kΩ	3	0.15	0.25
2SB1394/2SD2099		40	30	3	☆1.5	2	0.5	min70 RBE=typ0.8kΩ	1	50mA	0.18/0.12
2SB1396*		15	10	3	☆1.3	2	0.5	140~560	1.5	30mA	0.22
2SB1397/2SD2100		25	20	2	☆1.3	2	0.5	min70 RBE=typ1.6kΩ	1	50mA	0.25
2SD1620		30	10	3	☆1.3	2	3	typ210	3	60mA	0.3
2SD1628		60	20	5	☆1.5	2	0.5	120~560	3	60mA	0.5
2SB808/2SD1012	SPA	20	15	0.7	0.25	2	50mA	160~560/160~960	5mA	0.5mA	15mA/10mA
2SB1296/2SD1936		15	15	0.8	0.3	2	50mA	140~560/140~800	5mA	0.5mA	10mA
2SB698/2SD734	NP	25	20	0.7	0.6	2	50mA	60~560	0.5	50mA	0.2/0.13
2SB893		20	10	2.5	0.75	2	0.5	100~560	1.5	0.15	0.25
2SB926/2SD1246*		30	25	2	0.75	2	0.1	100~560	1.5	75mA	0.35/0.18
2SB1229/2SD1835*		60	50	2	0.75	2	0.1	100~560	1	50mA	0.3/0.15
2SB1395*		15	10	3	0.75	2	0.5	140~560	1.5	30mA	0.22
2SD879		30	10	3	0.75	2	3	typ210	3	60mA	0.3

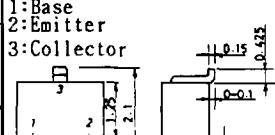
These specifications are subject to change without notice.

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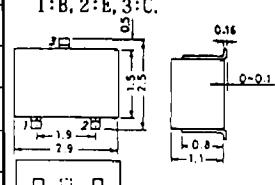
Case Outlines

(unit:mm)

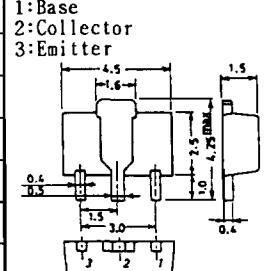
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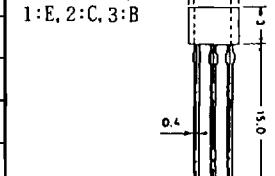
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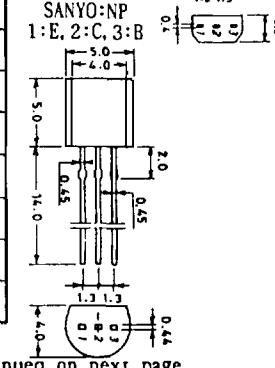
SANYO:PCP



SANYO:SPA



SANYO:NP



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LOW-SATURATION VOLTAGE TR SERIES(Small-Signal Transistors.NO.2)

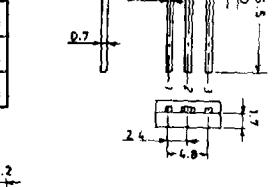
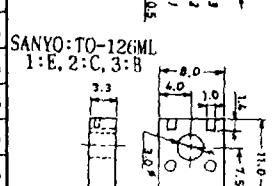
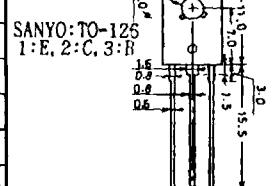
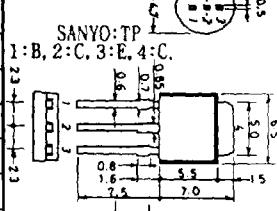
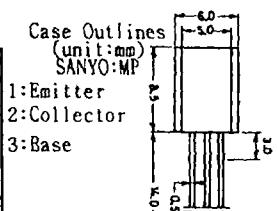
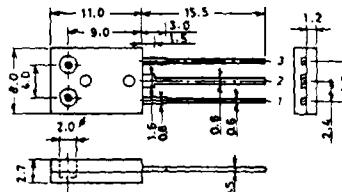
(*)MBIT process technology "New manufacturing method, Multi Base Island Transistors"

*: $T_c = 25^\circ\text{C}$, ●: Contains base to emitter resistance(RBE).

For PNP, (-) sign is omitted.

Type No.	Packa-	Absolute Maximum Ratings/ $T_a = 25^\circ\text{C}$				Electrical Characteristics/ $T_a = 25^\circ\text{C}$					
		V_{CBO} (V)	V_{CEO} (V)	I_C (A)	P_C (W)	V_{CE} (V)	I_C (A)	h_{FE}	I_C (A)	I_B (A)	$V_{CE(sat)}$ typ (V)
PNP/NPN	MP	60	50	1	0.9	2	50mA	60~320	0.5	50mA	0.2/0.15 0.7/0.5
2SB764/2SD863		60	50	2	1	2	0.1	100~560	1	50mA	0.3/0.15 0.7/0.4
2SB892/2SD1207*		30	25	2.5	1	2	0.1	100~560	1.5	75mA	0.35/0.18 0.6/0.4
2SB927/2SD1247*		60	50	3	1	2	0.1	100~560	2	0.1	0.35/0.19 0.7/0.5
2SB985/2SD1347*		25	20	5	1	2	0.5	100~400	3	60mA	0.25 0.5
2SB1131*		60	20	5	0.9	2	0.5	100~560	3	60mA	0.1...0.5
2SD1145	TP	25/30	20	8	**15	2	0.5	100~400	5	0.25	0.22 0.4
2SA1641/2SC4306*		60	50	2	**15	2	0.1	100~560	1	50mA	0.3/0.15 0.7/0.4
2SB1201/2SD1801*		60	50	3	**15	2	0.1	100~560	2	0.1	0.35/0.19 0.7/0.5
2SB1202/2SD1802*		60	50	5	**20	2	0.5	70~400	3	0.15	0.28/0.22 0.55/0.4
2SB1203/2SD1803*		60	50	8	**20	2	0.5	70~400	4	0.2	0.25/0.2 0.5/0.4
2SB1204/2SD1804*		25	20	5	**10	2	0.5	100~400	3	60mA	0.25 0.5
2SB1205*		120	100	3	**20	5	0.5	70~400	1.5	0.15	0.2/0.15 0.5/0.4
2SB1215/2SD1815*		120	100	4	**20	5	0.5	70~400	2	0.2	0.2/0.15 0.5/0.4
2SB1216/2SD1816*		60	20	5	**15	2	0.5	120~560	3	60mA	0.22 0.5
2SD1805		40	30	2	**15	0.5	0.5	min50 RBE=typlk2	2	40mA	0.25 0.5
2SD1806	FLP	25/30	20	8	1.5	2	0.5	100~400	5	0.25	0.22 0.4
2SA1823/2SC4727*		60	50	5	1.5	2	0.5	100~400	3	0.15	0.28/0.22 0.55/0.4
2SA1824/2SC4728*		60	50	8	1.5	2	0.5	100~400	4	0.2	0.25/0.2 0.5/0.4
2SA1825/2SC4729*		120	100	3	1.5	5	0.5	100~400	1.5	0.15	0.2/0.15 0.5/0.4
2SA1826/2SC4730*		120	100	4	1.5	5	0.5	100~400	2	0.2	0.2/0.15 0.5/0.4
2SA1827/2SC4731*		25	20	5	1.5	2	0.5	100~400	3	0.06	0.25 0.5
2SC4836		60	20	5	1.5	2	0.5	120~560	3	0.06	0.5
2SA1855/2SC4837*	TO-126	60	50	4	1.5	2	0.1	100~400	2	0.1	0.35/0.19 0.7/0.5
2SB986/2SD1348*		60	50	4	**10	2	0.1	100~560	2	0.1	0.35/0.19 0.7/0.5
2SB1127*		25	20	5	**10	2	0.5	100~400	3	60mA	0.25 0.5
2SD826		60	20	5	**10	2	0.5	120~560	3	60mA	0.1...0.5
2SA1798/2SC4675*	TO-126 ML	25/30	20	8	**10	2	0.5	100~400	5	0.25	0.22 0.4
2SB1140*		25	20	5	**10	2	0.5	100~400	3	60mA	0.25 0.5
2SB1141/2SD1681		20	18	1.2	**10	2	0.1	70~400	0.5	50mA	0.17/0.12 0.4/0.3
2SB1142/2SD1682*		60	50	2.5	**10	2	0.1	100~400/100~560	1	50mA	0.25/0.11 0.5/0.3
2SB1143/2SD1683*		60	50	4	**10	2	0.1	100~560	2	0.1	0.35/0.19 0.7/0.5
2SB1144/2SD1684*		120	100	1.5	**10	5	0.1	100~400	0.5	50mA	0.1/0.18 0.3/0.5
2SD1685		60	20	5	**10	2	0.5	120~560	3	60mA	0.22 0.5
2SB1165/2SD1722*	TO-126 LP	60	50	5	**20	2	0.5	70~400	3	0.15	0.28/0.22 0.55/0.4
2SB1166/2SD1723*		60	50	8	**20	2	0.5	70~400	4	0.2	0.25/0.2 0.5/0.4
2SB1167/2SD1724*		120	100	3	**20	5	0.5	70~400	1.5	0.15	0.2/0.15 0.5/0.4
2SB1168/2SD1725*		120	100	4	**20	5	0.5	70~400	2	0.2	0.2/0.15 0.5/0.4

SANYO:TO-126LP
1:E, 2:C, 3:B



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